

53 SERIES

SiC MOSFET 3300V.1a



APPLICATIONS

BMSBattery
Management
System**ESS**Energy
Storage
System**ATE**Automatic
Test
Equipment**HVS**High
Voltage
Switching

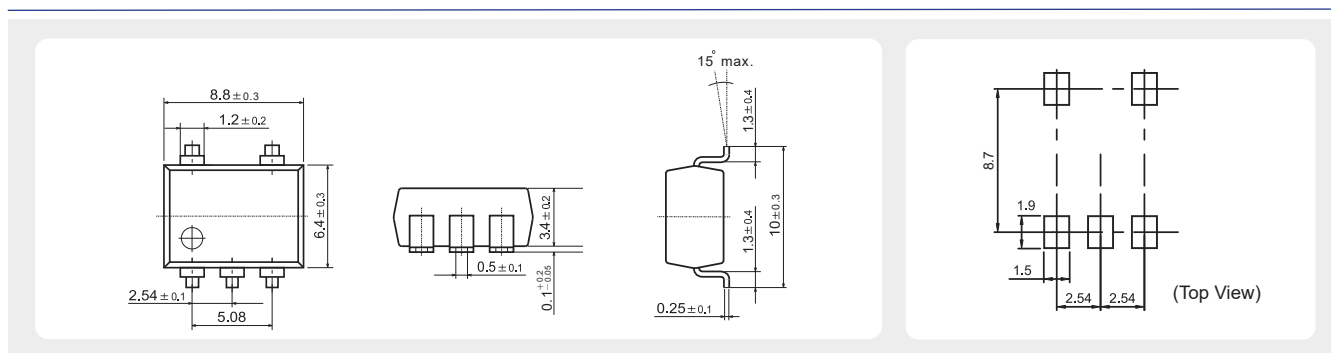
SPECIFICATIONS

ITEM	PERFORMANCE CHARACTERISTICS
Contact Form	1a
Load Voltage	3300V
Operation LED Current	5.0mA
Load Current	300mA
On-Resistance	3.5Ω
Output Capacitance	220pF
Low Off-State Leakage Current	1μA

PIN DESCRIPTION & PART NUMBER

CIRCUIT DIAGRAM	PIN DESCRIPTION	PART NO.	PACKAGE	PACKING
	1: Anode (+) • LED 2: Cathode (-) • LED 3: NC 4: Drain • MOSFET 6: Drain • MOSFET	AA53 AA53F AA53F-R1	DIP6-5 SMD6-5 SMD6-5	Tube 50pcs Tube 50pcs Reel 1000pcs

DIMENSIONS & PC BOARD PATTERN



ABSOLUTE MAXIMUM RATINGS (Ambient Temperature 周圍溫度 : 25°C)

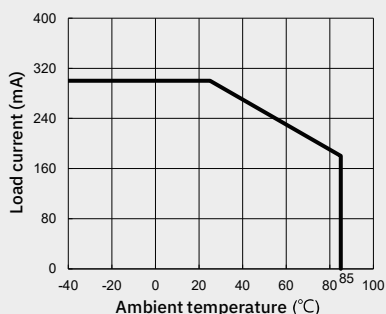
ITEM		CONDITION	SYMBOL	VALUE	UNIT
Input 輸入	Continuous LED Current 連續 LED 電流		I _F	50	mA
	Peak LED Current LED 峰值電流	100 Hz, Duty 1%	I _{FP}	500	mA
	LED Reverse Voltage 逆向 LED 電壓		V _R	5	V
	Input Power Dissipation 輸入損耗		P _{IN}	75	mW
Output 輸出	Load Voltage 負荷電壓		V _L	3300 (AC peak or DC)	V
	Load Current 負荷電流		I _L	300	mA
	Peak Load Current 峰值負荷電流	10 ms, 1 shot	I _{PEAK}	900	mA
	Output Power Dissipation 輸出損耗		P _{OUT}	550	mW
Relay 繼電器	Total Power Dissipation 全損耗		P _T	600	mW
	I/O Breakdown Voltage 輸入/出力間絕緣電壓		V _{I/O}	5000	V _{rms}
	Operating Temperature 使用時溫度		T _{OPR}	-40 ~ +105	°C
	Storage Temperature 保存溫度		T _{STG}	-40 ~ +100	°C

ELECTRICAL SPECIFICATIONS (Ambient Temperature 周圍溫度 : 25°C)

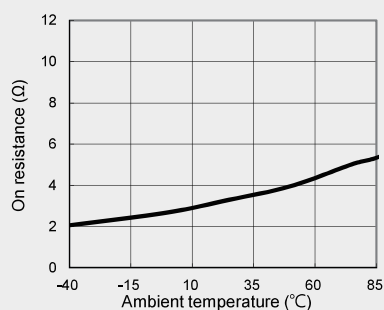
ITEM		CONDITION	SYM.	MIN.	TYP.	MAX.	UNIT
Input 輸入	LED Forward Voltage LED 順向電壓	I _F =10mA	V _F	1.0	1.33	1.5	V
	Operation LED Current LED 動作電流		I _{F ON}		2.4	5.0	mA
	Recovery LED Voltage LED 復位電壓		V _{F OFF}	0.5	1.2		V
Output 輸出	On-Resistance 導通電阻 Drain to Drain (Tested within 1 sec.)	I _F =10mA, I _L =Rating	R _{ON}		3.5	5	Ω
	Off-State Leakage Current 開路狀態漏電流	V _L =3300V	I _{LEAK}			1	μA
	Output Capacitance 輸出端容量	V _L =0V, f=1 MHz	C _{OUT}		220		pF
Transmission 傳達	Turn-On Time 動作時間	I _F =10mA, I _L =Rating	T _{ON}		1.0	3.0	ms
	Turn-Off Time 復位時間		T _{OFF}		0.05	1.0	ms
Coupled 結合	I/O Insulation Resistance 輸入/ 出間絕緣阻抗		R _{I/O}	10 ¹⁰			Ω
	I/O Capacitance 輸入/ 力端靜電容量	f=1MHz	C _{I/O}		1.3		pF

REFERENCE DATA

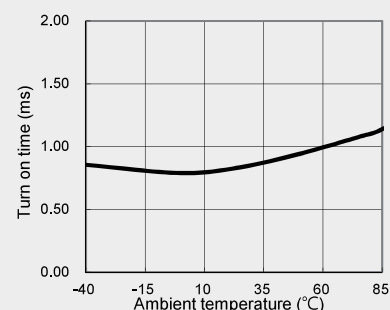
Load current vs. Ambient temp.



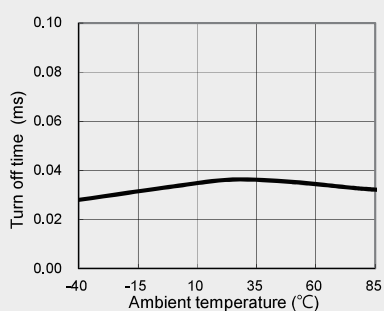
On resistance vs. Ambient temp.



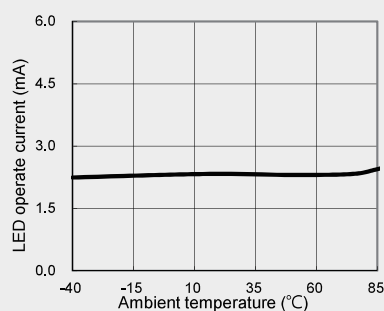
Turn on time vs. Ambient temp.



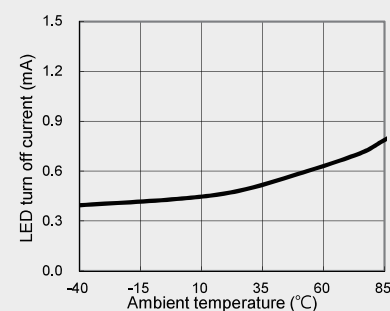
Turn off time vs. Ambient temp.



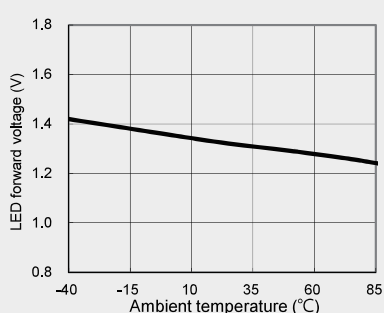
LED operate current vs. Ambient temp.



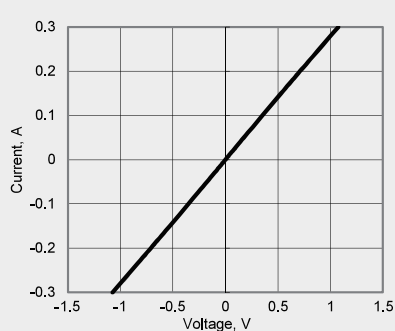
LED turn off current vs. Ambient temp.



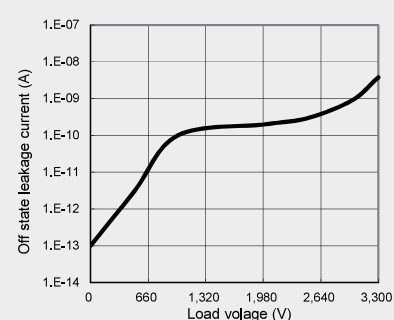
LED forward voltage vs. Ambient temp.



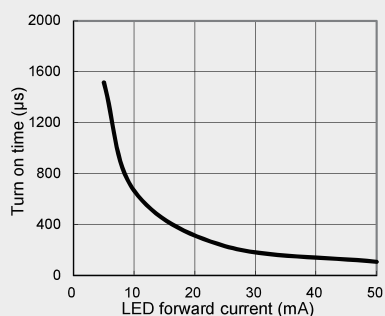
Current vs. Voltage characteristics of output at MOS portion



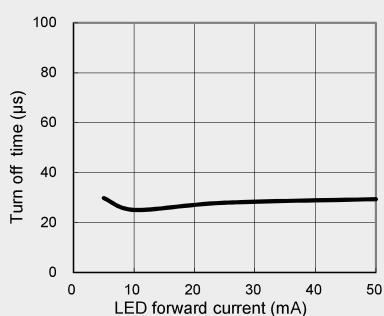
Off state leakage current vs. Load voltage



Turn on time vs. LED forward current



Turn off time vs. LED forward current



Output capacitance vs. Applied voltage

